

Dual N-channel 30 V, 5.8 mΩ logic level MOSFET

2 September 2015

Product data sheet

1. General description

Dual logic level N-channel MOSFET in an LFPAK56D (Dual Power-SO8) package using TrenchMOS technology. This product has been designed and qualified to AEC Q101 standard for use in high performance automotive applications.

2. Features and benefits

- Dual MOSFET
- Q101 Compliant
- Repetitive avalanche rated
- Suitable for thermally demanding environments due to 175 °C rating
- True logic level gate with $V_{GS(th)}$ rating of greater than 0.5 V at 175 °C

3. Applications

- 12 V Automotive systems
- Motors, lamps and solenoid control
- Transmission control
- Ultra high performance power switching

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	-	30	V
I _D	drain current	V _{GS} = 5 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	40	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	64	W
Static character	eristics FET1 and FET2						
R _{DSon}	drain-source on-state resistance	V _{GS} = 5 V; I _D = 10 A; T _j = 25 °C; <u>Fig. 11</u>		-	4.7	5.8	mΩ
Dynamic characteristics FET1 and FET2							
Q _{GD}	gate-drain charge	I_D = 10 A; V_{DS} = 24 V; V_{GS} = 5 V; T_j = 25 °C; Fig. 13; Fig. 14		-	9.2	-	nC

[1] Continuous current is limited by package

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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S1	source1	8 7 6 5	
2	G1	gate1		
3	S2	source2		
4	G2	gate2		
5	D2	drain2		 S1 G1 S2 G2
6	D2	drain2		mbk725
7	D1	drain1	1 2 3 4 LFPAK56D (SOT1205)	
8	D1	drain1	(0011200)	

6. Ordering information

Table 3. Ordering information							
Type number	Package	skage					
	Name	Description	Version				
BUK9K5R6-30E	LFPAK56D	Plastic single ended surface mounted package (LFPAK56D); 8 leads	SOT1205				

7. Marking

Table 4. Marking codes	
Type number	Marking code
BUK9K5R6-30E	95E630

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C		-	30	V
V _{DGR}	drain-gate voltage	R _{GS} = 20 kΩ		-	30	V
V _{GS}	gate-source voltage	T _j ≤ 175 °C; DC		-10	10	V
		$T_j \le 175 \ ^{\circ}C; Pulsed$	[1][2]	-15	15	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	64	W
I _D	drain current	T_{mb} = 25 °C; V_{GS} = 5 V; Fig. 2	[3]	-	40	А
		T _{mb} = 100 °C; V _{GS} = 5 V; <u>Fig. 2</u>	[3]	-	40	А
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Symbol	Parameter	Conditions		Min	Max	Unit
I _{DM}	peak drain current	T_{mb} = 25 °C; pulsed; $t_p \le 10 \ \mu s$; Fig. 3		-	305	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain	diode FET1 and FET2					
I _S	source current	T _{mb} = 25 °C	[3]	-	40	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^\circ C$		-	305	А
Avalanche R	uggedness FET1 and FET2					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	$\label{eq:ID} \begin{split} I_D &= 40 \text{ A}; \text{V}_{sup} \leq 30 \text{V}; \text{R}_{GS} = 50 \Omega; \\ \text{V}_{GS} &= 5 \text{V}; \text{T}_{j(\text{init})} = 25 ^{\circ}\text{C}; \text{ unclamped}; \\ \hline \text{Fig. 4} \end{split}$	[4][5]	-	169	mJ

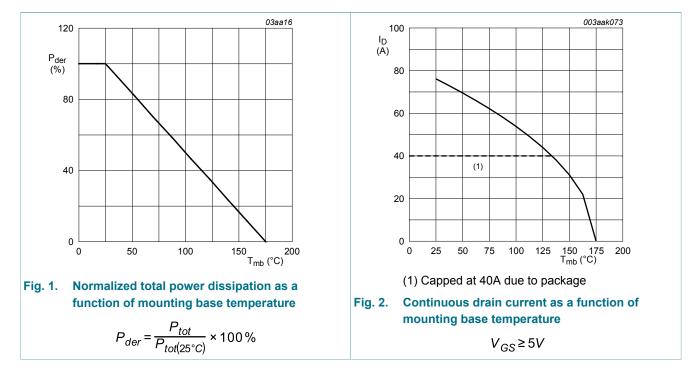
[1] Accumulated Pulse duration up to 50 hours delivers zero defect ppm

[2] Significantly longer life times are achieved by lowering T_j and or V_{GS} .

[3] Continuous current is limited by package

[4] Refer to application note AN10273 for further information

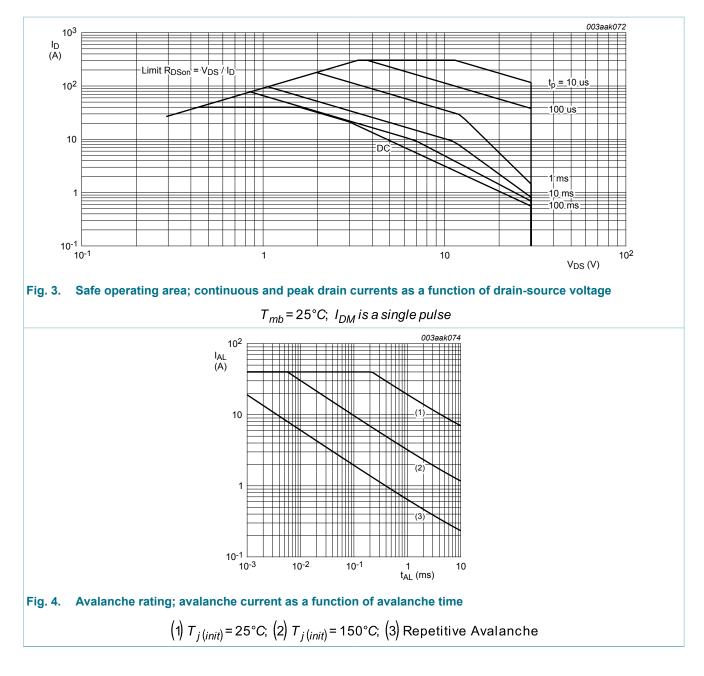
[5] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C



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9. Thermal characteristics

lable 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>		-	-	2.36	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	Minimum footprint; mounted on a printed circuit board		-	95	-	K/W

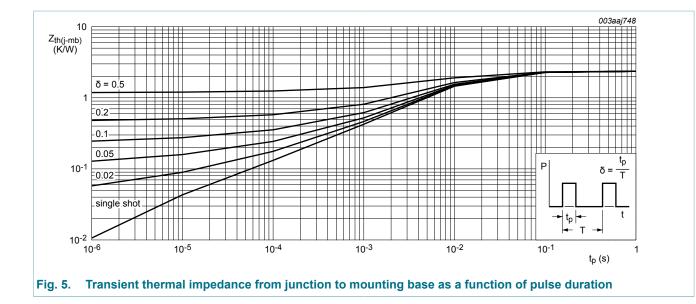
Table 6. Thermal characteristics

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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics FET1 and FET2	· · · ·	I			
V _{(BR)DSS}	drain-source	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C	27	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	30	-	-	V
V _{GS(th)}	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS} ; T_j = 25 °C; Fig. 9; Fig. 10	1.4	1.7	2.1	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ Fig. 9	0.5	-	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 9	-	-	2.45	V
I _{DSS}	drain leakage current	V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25 °C	-	0.02	1	μA
		V _{DS} = 30 V; V _{GS} = 0 V; T _j = 175 °C	-	-	500	μA
I _{GSS} gate leakage	gate leakage current	V_{GS} = -10 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
		V_{GS} = 10 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
Doon	drain-source on-state	V _{GS} = 5 V; I _D = 10 A; T _j = 25 °C; <u>Fig. 11</u>	-	4.7	5.8	mΩ
	resistance	V _{GS} = 5 V; I _D = 10 A; T _j = 175 °C; Fig. 11; Fig. 12	-	8.9	11	mΩ
		V _{GS} = 10 V; I _D = 10 A; T _j = 25 °C; Fig. 11	-	3.9	4.7	mΩ
Dynamic ch	naracteristics FET1 and FE	T2	I			
Q _{G(tot)}	total gate charge	I_D = 10 A; V_{DS} = 24 V; V_{GS} = 5 V;	-	22.6	-	nC
Q _{GS}	gate-source charge	T _j = 25 °C; <u>Fig. 13; Fig. 14</u>	-	4.4	-	nC

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Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Q _{GD}	gate-drain charge			-	9.2	-	nC
C _{iss}	input capacitance	V _{GS} = 0 V; V _{DS} = 25 V; f = 1 MHz;		-	1860	2480	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 15</u>		-	391	469	pF
C _{rss}	reverse transfer capacitance			-	231	316	pF
t _{d(on)}	turn-on delay time	V_{DS} = 24 V; R_L = 2.4 Ω ; V_{GS} = 5 V; $R_{G(ext)}$ = 5 Ω ; T_j = 25 °C		-	13.8	-	ns
t _r	rise time			-	25.2	-	ns
t _{d(off)}	turn-off delay time	-		-	30.1	-	ns
t _f	fall time			-	22.4	-	ns
Source-dra	ain diode FET1 and FET2						
V _{SD}	source-drain voltage	I_{S} = 10 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 16</u>		-	0.78	1.2	V
t _{rr}	reverse recovery time	$I_{S} = 10 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$ $V_{DS} = 15 \text{ V}; \text{ T}_{j} = 25 \text{ °C}$		-	32.3	-	ns
Qr	recovered charge			-	26.7	-	nC

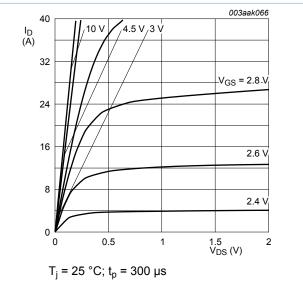


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

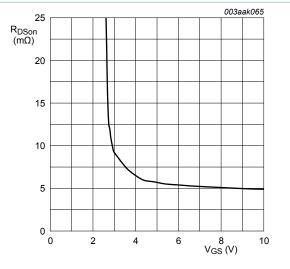


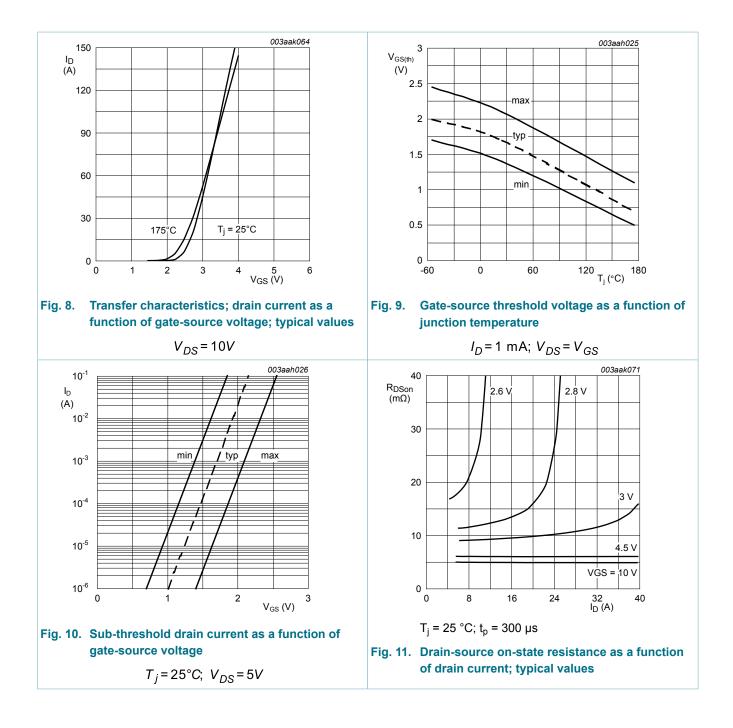
Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

 $T_j = 25^{\circ}C; I_D = 10A$

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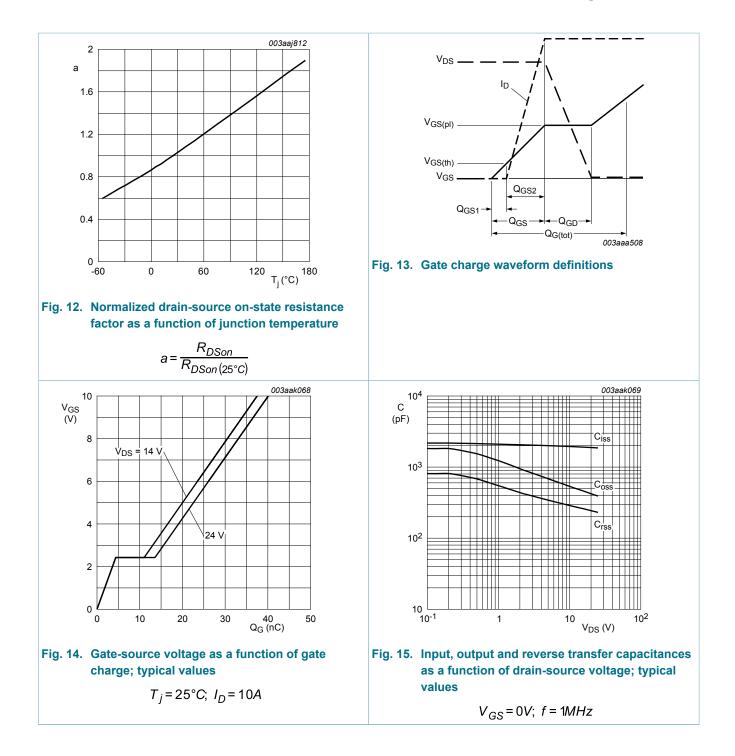
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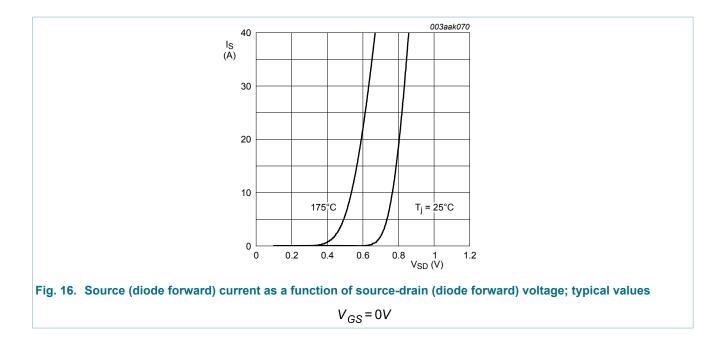
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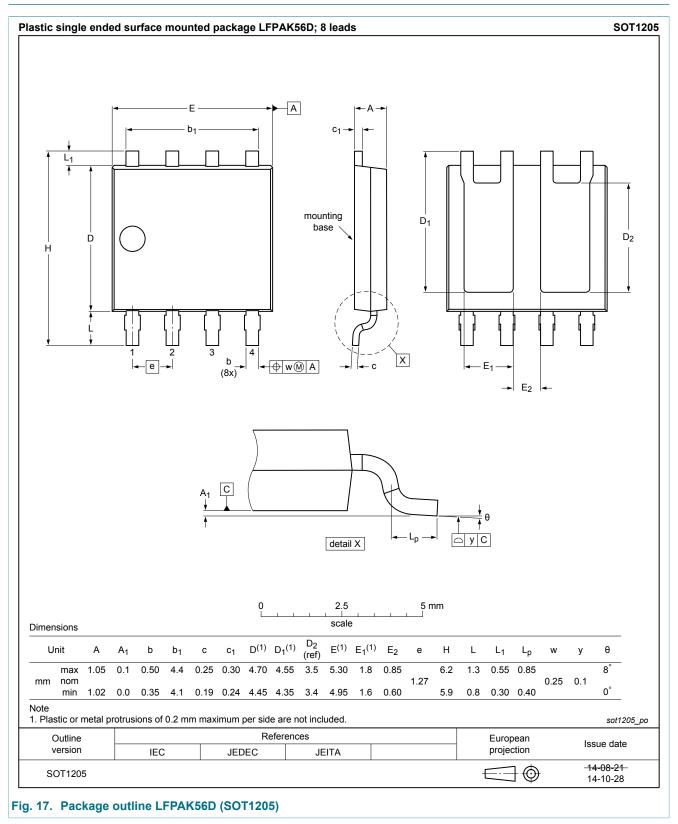
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11. Package outline



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Product data sheet

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12. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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